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PATENT
Attorney Docket No.: 018865-003200US
Client Reference No.: 17732-9345.00

On January 10, 2000

TOWNSEND and TOWNSEND and CREW LLP

By: Sherry Barton



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w/ Drugs.
Marsha
1/26/01

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:

Bruce D. Marchant, et al.

Application No.: 09/405,210

Filed: September 24, 1999

For: METHOD OF MANUFACTURING
TRENCH FIELD EFFECT
TRANSISTORS WITH TRENCHED
HEAVY BODY

Examiner: VU, D.

Art Unit: 2818

AMENDMENT

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Assistant Commissioner for Patents
Washington, D.C. 20231

Sir:

In response to the Office Action mailed October 25, 2000, please amend the above-identified application as follows:

IN THE SPECIFICATION:

a' On page ⁴6, line 20, insert the following: --Figure 2C shows a trench field effect transistor, according to an alternative embodiment of present invention; --.

a.2 On page 7, line, replace "Similarly, by varying heavy body trench profile, the edge" with --Similarly, as shown in Figure 2C, by varying the heavy body trench profile, the edge 203--.

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